

DATA SHEET

SA631

1GHz low voltage LNA and mixer

Product specification

1998 Jan 08

IC17 Data Handbook

1GHz low voltage LNA and mixer

SA631

DESCRIPTION

The SA631 is a combined low-noise BiCMOS amplifier, and mixer designed for high-performance low-power communication systems from 800-1000MHz. The low-noise preamplifier has a 1.7dB noise figure at 881MHz with 15dB gain and an IP3 intercept of -7dBm at the input. The gain is stabilized by on-chip compensation to vary less than $\pm 0.2\text{dB}$ over -40 to $+85^\circ\text{C}$ temperature range. The wide-dynamic-range mixer has a 10dB noise figure and IP3 of $+3.3\text{dBm}$ at the input at 881MHz. The nominal current drawn from a single 3V supply is 8.3mA. Additionally, the entire circuit can be powered down to further reduce the supply current to less than $20\mu\text{A}$.

FEATURES

- Low current consumption
- Outstanding gain and noise figure
- Excellent gain stability versus temperature and supply voltage
- LNA and mixer power down capability
- Designed in Philips state of the art BiCMOS QUBIC process

APPLICATIONS

- 900MHz cellular and cordless front-end
- Spread spectrum receivers
- RF data links
- UHF frequency conversion
- Portable radio

ORDERING INFORMATION

DESCRIPTION	TEMPERATURE RANGE	ORDER CODE	DWG #
20-Pin Shrink Small Outline Package (Surface-mount, SSOP)	-40 to $+85^\circ\text{C}$	SA631DK	SOT266-1

BLOCK DIAGRAM

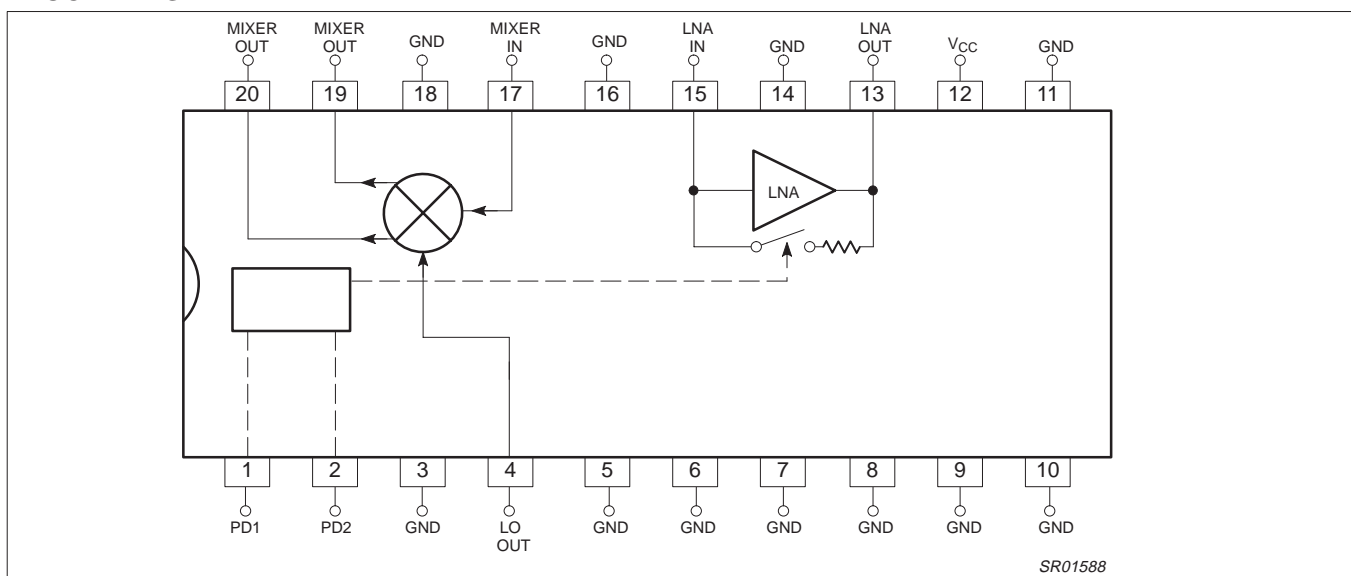


Figure 2. SA631 Block Diagram

PIN CONFIGURATION

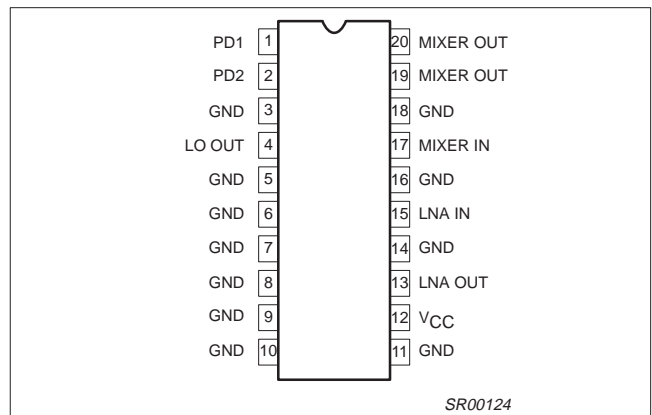


Figure 1. Pin Configuration

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ABSOLUTE MAXIMUM RATINGS

SYMBOL	PARAMETER	RATING	UNITS
V_{CC}	Supply voltage ¹	-0.3 to +6	V
V_{IN}	Voltage applied to any other pin	-0.3 to ($V_{CC} + 0.3$)	V
P_D	Power dissipation, $T_{amb} = 25^\circ\text{C}$ (still air) ² 20-Pin Plastic SSOP	980	mW
T_{JMAX}	Maximum operating junction temperature	150	$^\circ\text{C}$
P_{MAX}	Maximum power input/output	+20	dBm
T_{STG}	Storage temperature range	-65 to +150	$^\circ\text{C}$

NOTES:

- Transients exceeding 8V on V_{CC} pin may damage product.
- Maximum dissipation is determined by the operating ambient temperature and the thermal resistance,
 θ_{JA} : 20-Pin SSOP = 110°C/W
- Pins 19 and 20 are ESD sensitive (mixer outputs).

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	RATING	UNITS
V_{CC}	Supply voltage	2.7 to 5.5	V
T_{amb}	Operating ambient temperature range	-40 to +85	$^\circ\text{C}$
T_J	Operating junction temperature	-40 to +105	$^\circ\text{C}$

DC ELECTRICAL CHARACTERISTICS

 $V_{CC} = +3.0\text{V}$, $T_{amb} = 25^\circ\text{C}$; unless otherwise stated.

SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNITS
			MIN	TYP	MAX	
I_{CC}	Supply current	Full power-on		8.3		mA
		LNA powered-down		5.2		mA
		Full power-down		20		μA
V_T	PD logic threshold voltage		1.2	1.6	1.8	V
V_{IH}	Logic 1 level		2.0		V_{CC}	V
V_{IL}	Logic 0 level		-0.3		0.8	V
I_{IL}	PD1 input current	Enable = 0.4V		10		μA
I_{IH}	PD2 input current	Enable = 2.4V		10		μA

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AC ELECTRICAL CHARACTERISTICS $V_{CC} = +3.0V$, $T_{amb} = 25^{\circ}C$; $RF_{IN} = 881MHz$, $f_{VCO} = 964MHz$; unless otherwise stated.

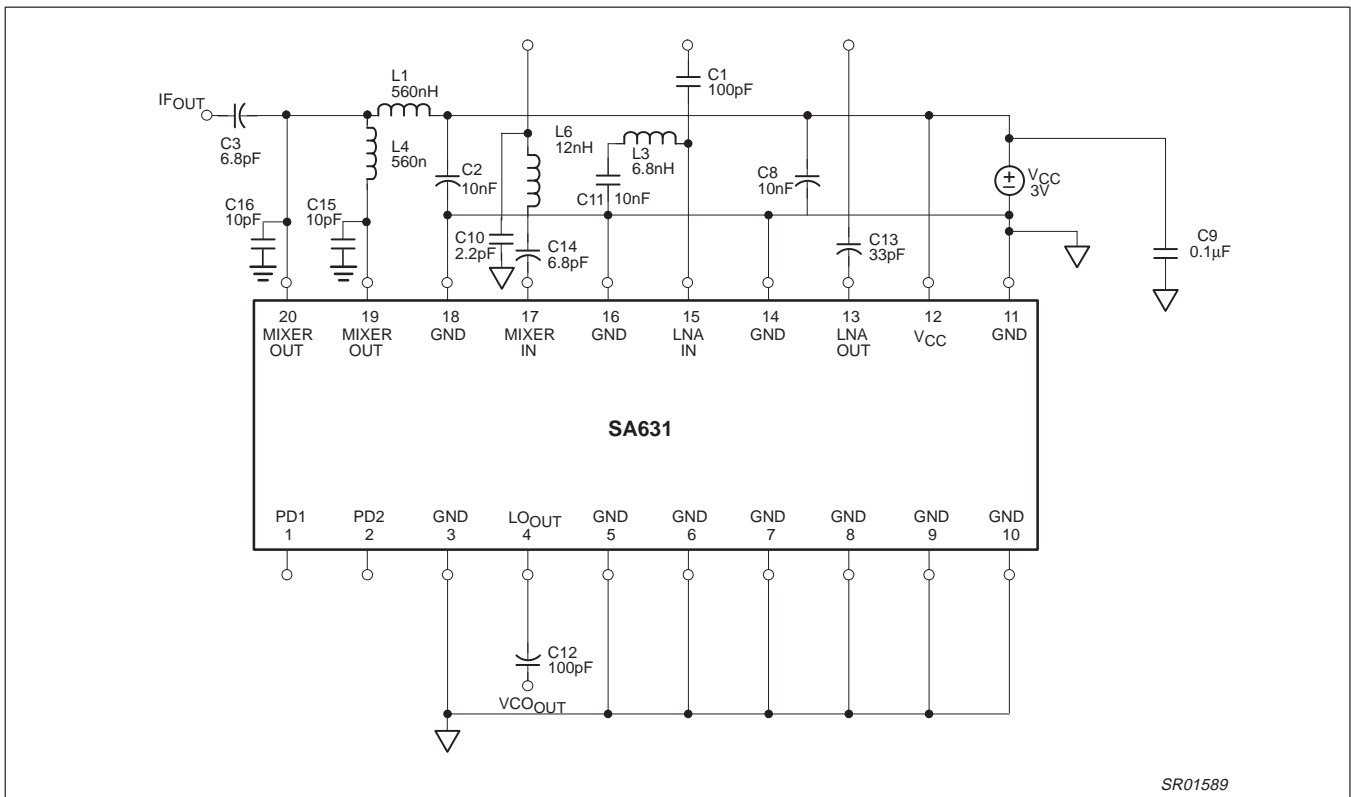
SYMBOL	PARAMETER	TEST CONDITIONS	LIMITS			UNITS
			-3 σ	TYP	+3 σ	
Low Noise Amplifier						
f_{RF}	RF input frequency range		800		1000	MHz
S_{21}	Amplifier gain			15		dB
S_{21}	Amplifier gain in power-down mode			-28		dB
$\Delta S_{21}/\Delta T$	Gain temperature sensitivity enabled			0.006		dB/ $^{\circ}C$
$\Delta S_{21}/\Delta f$	Gain frequency variation	800MHz - 1.0GHz		± 0.013		dB/MHz
S_{12}	Amplifier reverse isolation	@ 881 MHz		-28		dB
S_{11}	Amplifier input match	With ext. impedance matching		-10		dB
S_{22}	Amplifier output match			-10		dB
P_{-1dB}	Amplifier input 1dB gain compression			-20		dBm
IP3	Amplifier input third order intercept			-7		dBm
NF	Amplifier noise figure			1.7		dB
t_{ON}	Amplifier turn-on time (Enable Lo \rightarrow Hi)			120		μs
t_{OFF}	Amplifier turn-off time (Enable Hi \rightarrow Lo)			0.3		μs
Mixer						
PG_C	Mixer power conversion gain: $R_P = R_L = 1.2k\Omega$	$f_{RF} = 881MHz$, $f_{LO} = 964MHz$, $f_{IF} = 83MHz$		9.6		dB
S_{11M}	Mixer input match	Ext. impedance matching req.		-10		dB
NF_M	Mixer SSB noise figure			10		dB
P_{-1dB}	Mixer input 1dB gain compression			-14.5		dBm
IP3M	Mixer input third order intercept			3.3		dBm
IP2INT	Mixer input second order intercept			38		dBm
P_{RFM-IF}	Mixer RF feedthrough	$RF_{IN} = -32dBm$		-45		dBm
P_{LO-IF}	LO feedthrough to IF	$LO = -0dBm$		-23		dBm
P_{LO-RFM}	LO to mixer input feedthrough			-32		dBm
P_{LO-RF}	LO to LNA input feedthrough			-42		dBm
Overall System						
G_{SYS}	System gain	LNA + Mixer	23.9	24.6	25.3	dB

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Table 1. Power ON/OFF Control Logic

PD1	PD2	
0	0	Full chip power-down
0	1 or open	Mixer on, LNA power-down
1 or open	0	Standby (bias on)
1 or open	1 or open	Full chip power-on (default)



SR01589

Figure 3. SA631 Application Circuit

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PERFORMANCE CHARACTERISTICS

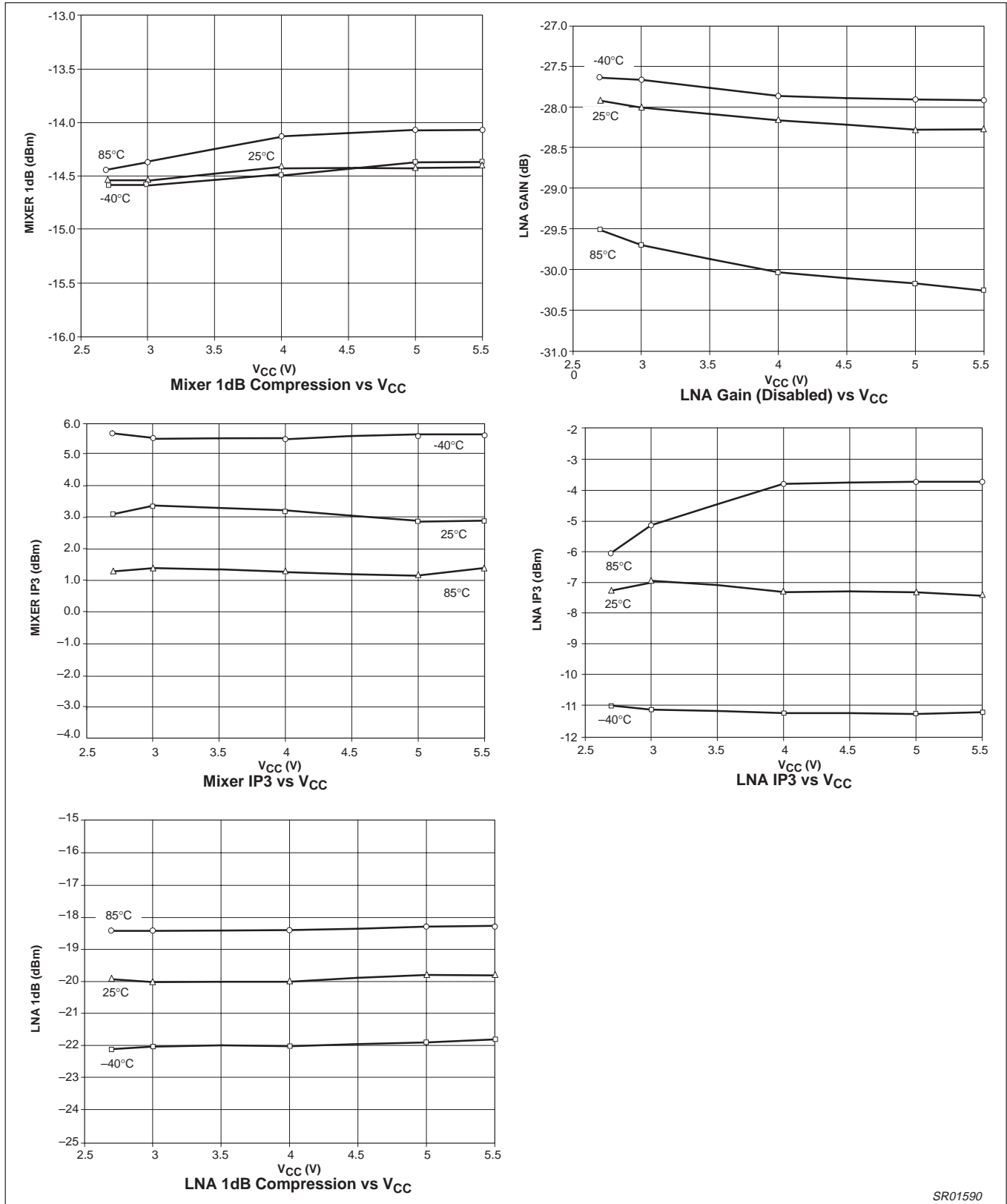


Figure 4.

SR01590

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PERFORMANCE CHARACTERISTICS

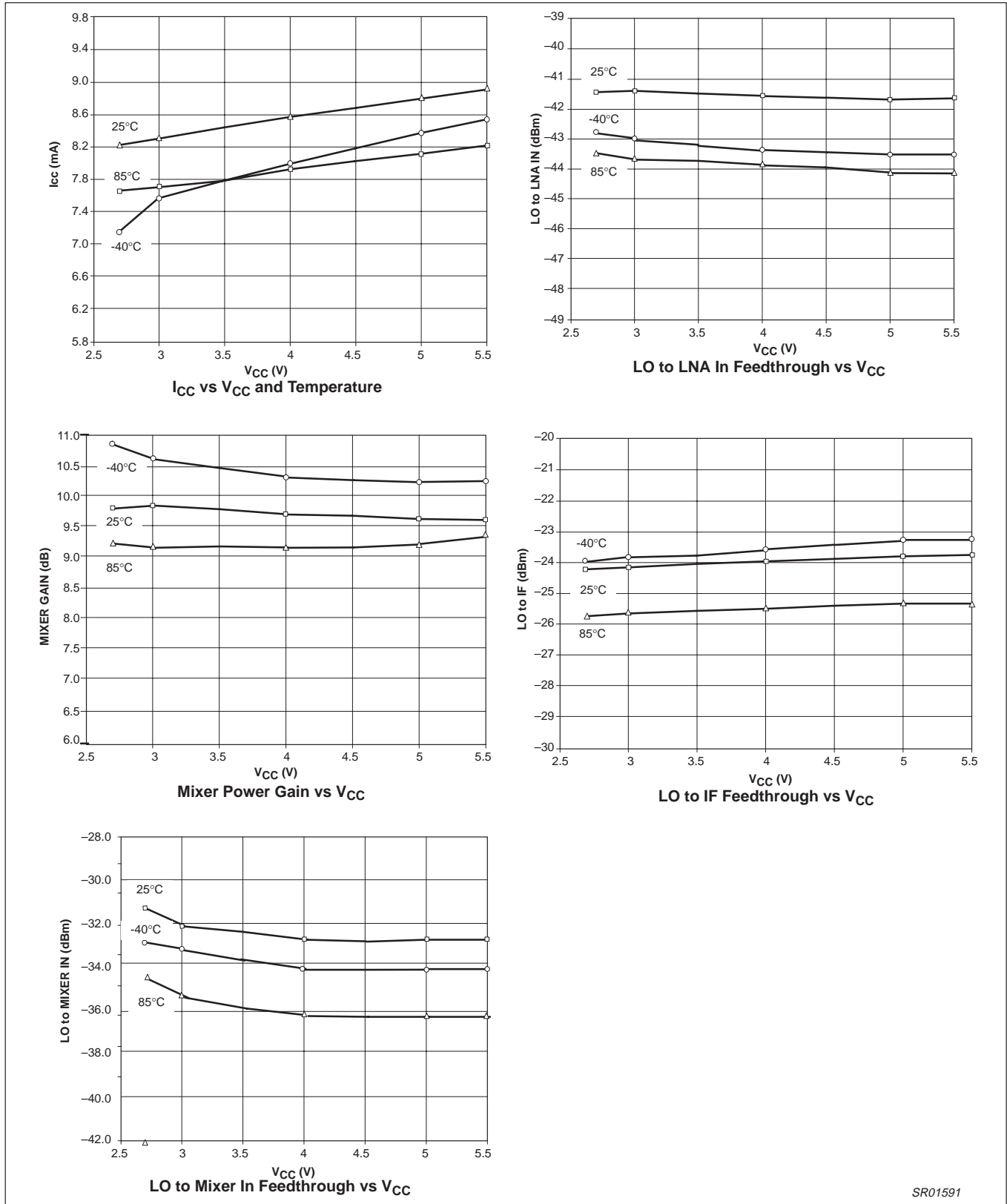
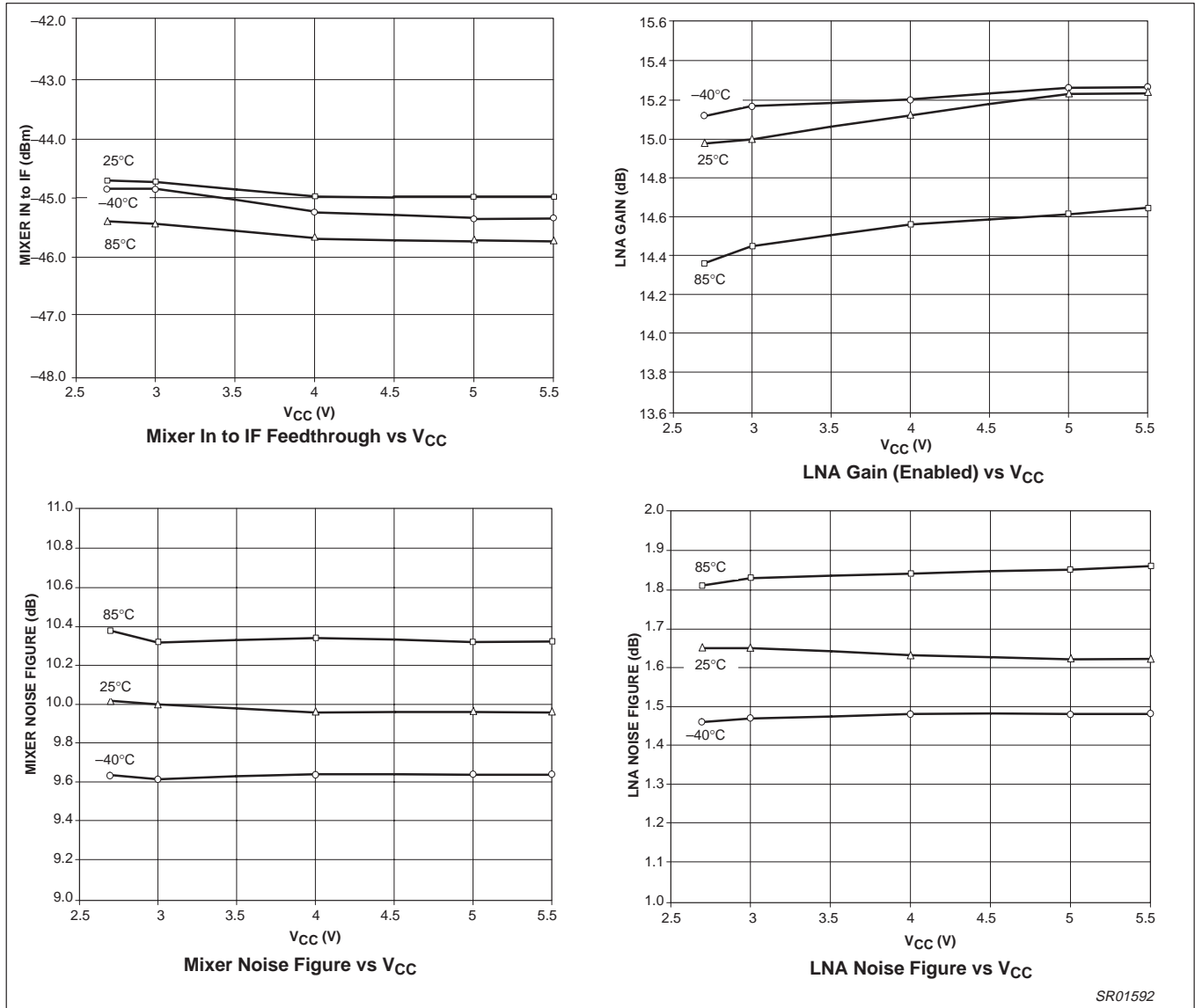


Figure 5.

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PERFORMANCE CHARACTERISTICS



SR01592

Figure 6.

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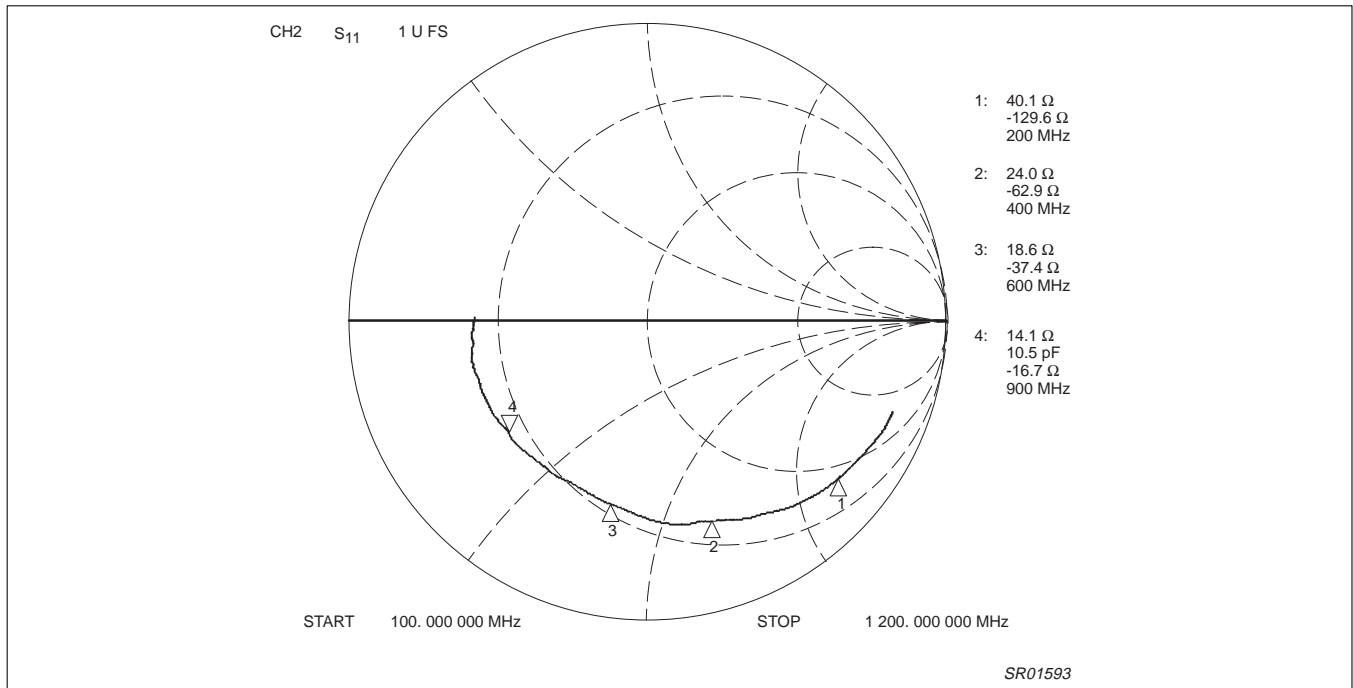


Figure 7. Typical S₁₁ of LNA at 3V

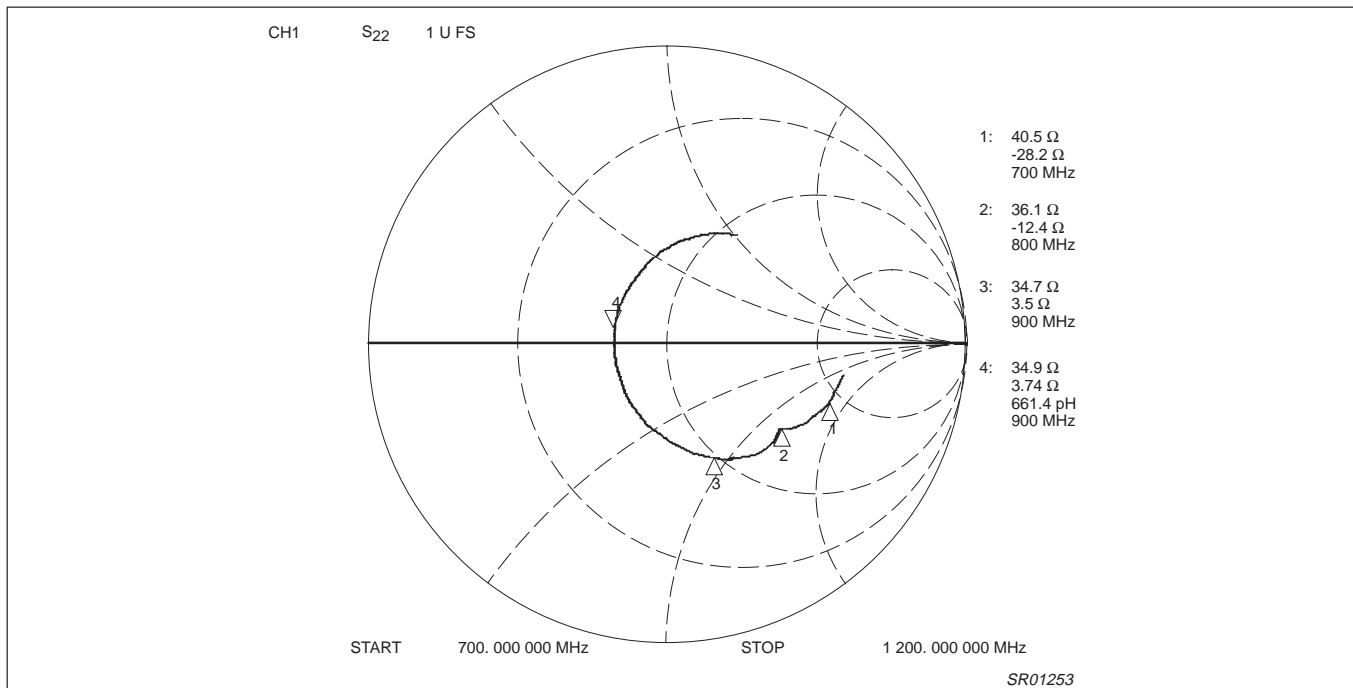


Figure 8. Typical S₂₂ of LNA at 3V

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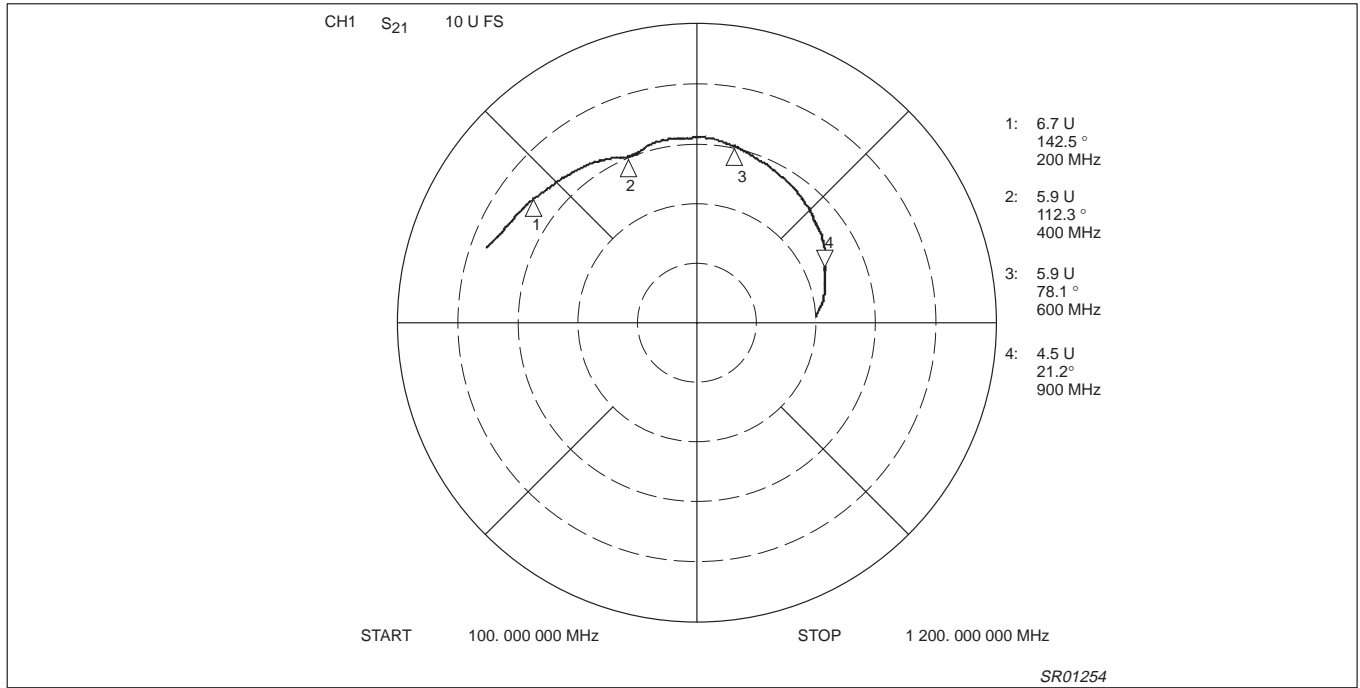


Figure 9. Typical S_{21} of LNA at 3V

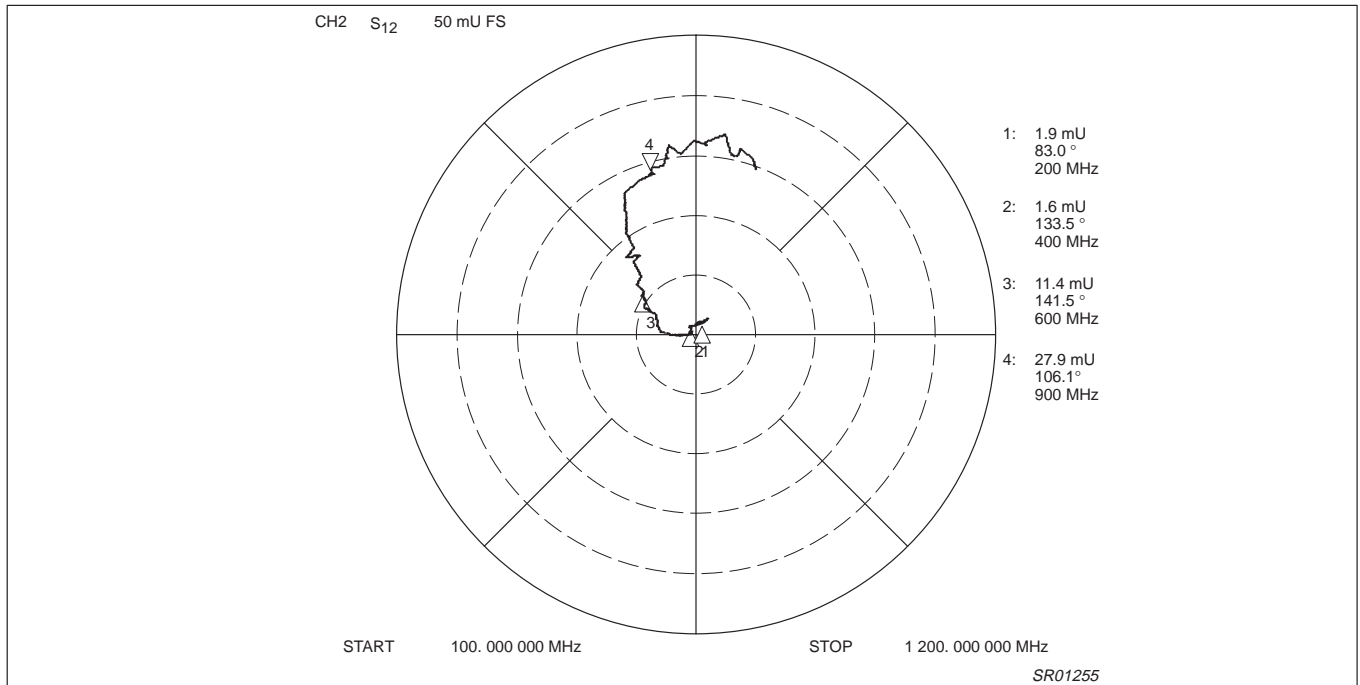


Figure 10. Typical S_{12} of LNA at 3V

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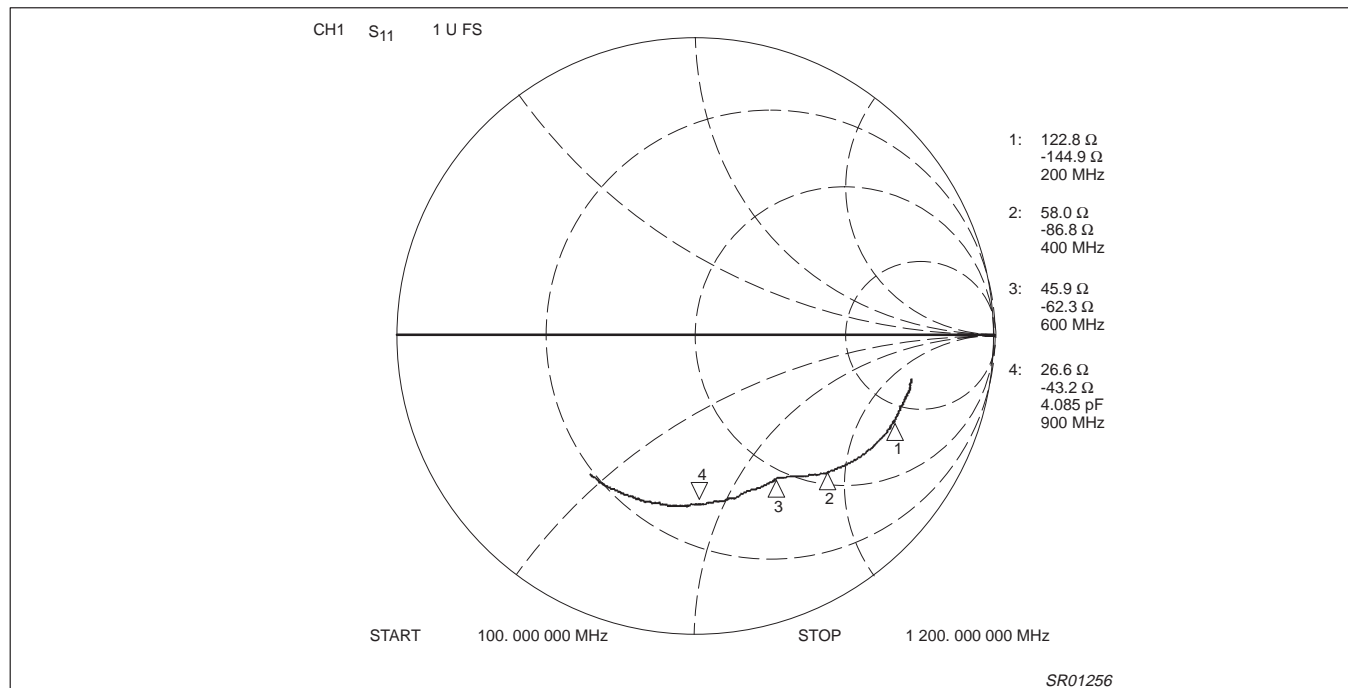


Figure 11. Typical S₁₁ of Mixer at 3V

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Table 2. Typical S-Parameters of LNA at 3V

LNA								
Freq (MHz)	S ₁₁ (U)	<S ₁₁ (deg)	S ₂₁ (U)	<S ₂₁ (deg)	S ₁₂ (U)	<S ₁₂ (deg)	S ₂₂ (U)	<S ₂₂ (deg)
100	0.86	-20	7.4	160	0.001	91.91	0.59	-9.62
122	0.86	-24	7.1	156	0.001	62	0.58	-11.71
144	0.85	-28	7.0	151	0.001	105.42	0.58	-13.86
166	0.83	-32	6.9	148	0.000	91.65	0.57	-15.89
188	0.82	-36	6.8	144	0.002	100.23	0.57	-17.80
210	0.81	-41	6.7	140	0.002	73.57	0.56	-20.05
232	0.80	-45	6.6	136	0.002	99.70	0.55	-22.37
254	0.79	-48	6.5	133	0.001	84.00	0.54	-24.60
276	0.78	-52	6.4	130	0.001	103.18	0.53	-26.89
298	0.76	-56	6.3	126	0.002	94.33	0.52	-28.72
320	0.75	-59	6.3	123	0.002	66.98	0.51	-30.98
342	0.73	-63	6.2	119	0.002	108.53	0.50	-32.79
364	0.71	-66	6.1	116	0.002	118.13	0.48	-34.68
386	0.70	-69	6.0	113	0.001	103.4	0.47	-36.06
408	0.69	-72	5.9	111	0.001	175.94	0.46	-36.64
430	0.68	-76	5.9	109	0.004	174.1	0.45	-37.21
452	0.69	-78	6.0	106	0.006	162.02	0.46	-38.41
474	0.68	-82	6.1	102	0.007	160.07	0.47	-41.54
496	0.67	-85	6.1	97	0.008	153.6	0.47	-45.75
518	0.66	-89	6.1	93	0.010	146.17	0.46	-50.35
540	0.65	-92	6.1	89	0.009	142.13	0.45	-54.73
562	0.63	-96	6.1	85	0.010	138.49	0.43	-59.16
584	0.62	-99	6.0	81	0.011	146.17	0.42	-63.93
606	0.62	-102	5.9	77	0.011	140.55	0.40	-68.56
628	0.61	-104	5.8	72	0.013	137.2	0.38	-73.48
650	0.61	-107	5.7	69	0.013	130.62	0.36	-78.19
672	0.60	-109	5.7	65	0.016	129.77	0.34	-83.75
694	0.60	-112	5.6	61	0.016	131.94	0.31	-89.81
716	0.59	-115	5.5	57	0.017	128.67	0.29	-96.92
738	0.59	-118	5.5	53	0.019	127.53	0.27	-104.48
760	0.59	-121	5.3	48	0.021	123.42	0.24	-112.81
782	0.59	-124	5.3	44	0.021	122.31	0.22	-122.41
804	0.59	-126	5.1	40	0.022	119.52	0.21	-132.81
826	0.59	-129	5.0	36	0.024	118.29	0.19	-145.39
848	0.59	-132	4.9	31	0.026	115.98	0.18	-159.13
870	0.59	-135	4.8	26	0.027	111.9	0.17	-175.11
892	0.59	-138	4.6	22	0.028	108.11	0.18	169.02
914	0.59	-142	4.5	18	0.028	105.92	0.19	154.96
936	0.59	-144	4.3	14	0.028	106.13	0.20	141.94
958	0.59	-148	4.2	9	0.030	99.79	0.22	130.27
980	0.59	-151	4.0	4	0.031	99.30	0.24	119.5
1002	0.59	-153	3.8	0	0.031	94.81	0.26	110.61
1024	0.59	-157	3.6	-2	0.032	90.91	0.28	102.16
1046	0.59	-160	3.5	-6	0.032	85.65	0.30	94.98
1068	0.59	-164	3.3	-10	0.033	86.10	0.33	88.45
1090	0.59	-167	3.2	-14	0.033	80.59	0.35	82.47
1112	0.59	-170	3.0	-18	0.031	79.18	0.36	77.17
1134	0.58	-172	2.8	-22	0.030	46.32	0.38	71.98
1156	0.58	-175	2.7	-25	0.031	78.57	0.39	67.45
1178	0.57	-178	2.5	-28	0.031	73.66	0.41	62.73
1200	0.57	178	2.4	-31	0.029	71.78	0.42	58.87

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Table 3. Typical S-Parameters of Mixer at 3V

Mixer		
Freq (MHz)	$ S_{11} $ (U)	$\angle S_{11}$ (deg)
100	0.73	-11
122	0.73	-147
144	0.72	-16
166	0.72	-19
188	0.72	-21
210	0.71	-24
232	0.70	-27
254	0.70	-29
276	0.69	-32
298	0.68	-34
320	0.67	-37
342	0.66	-39
364	0.64	-42
386	0.63	-44
408	0.62	-46
430	0.61	-48
452	0.59	-50
474	0.58	-52
496	0.57	-53
518	0.56	-54
540	0.55	-56
562	0.55	-57
584	0.54	-59
606	0.54	-61
628	0.54	-62
650	0.54	-64

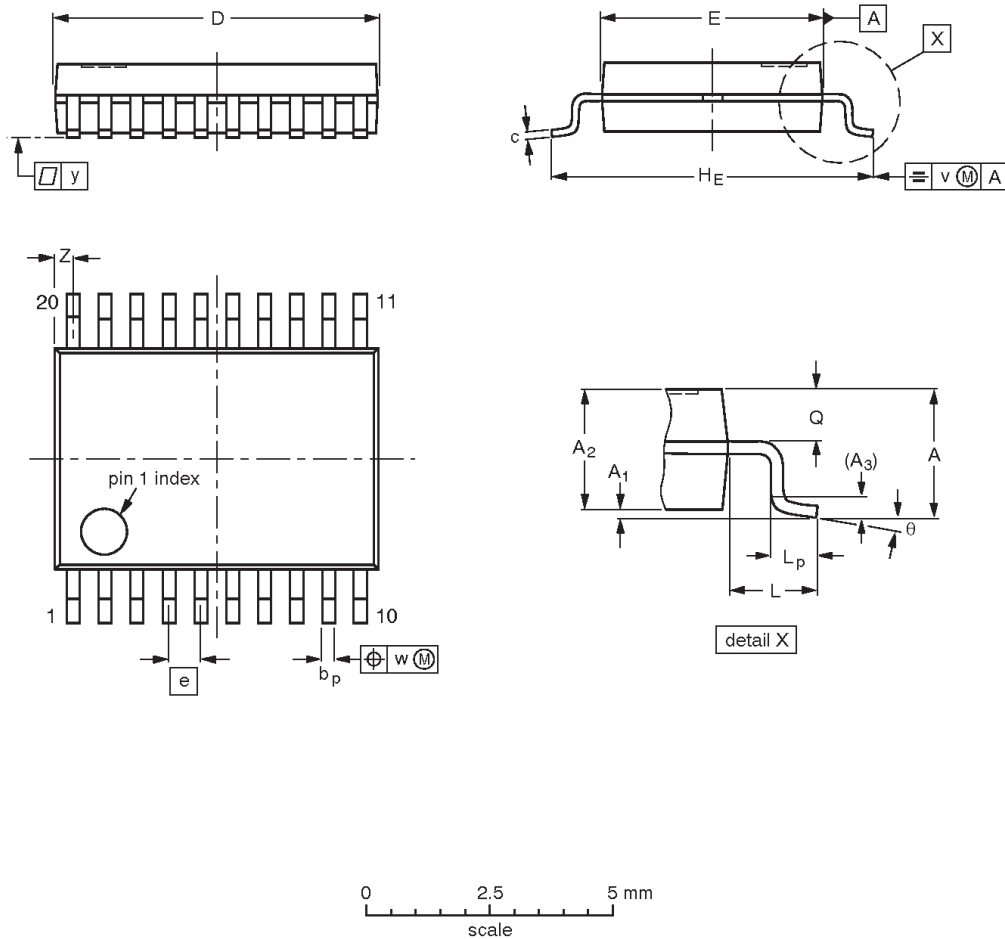
Mixer		
Freq (MHz)	$ S_{11} $ (U)	$\angle S_{11}$ (deg)
672	0.54	-65
694	0.54	-67
716	0.54	-69
738	0.54	-71
760	0.54	-73
782	0.55	-76
804	0.55	-78
826	0.55	-80
848	0.55	-82
870	0.55	-85
892	0.56	-87
914	0.55	-90
936	0.56	-93
958	0.56	-96
980	0.56	-98
1002	0.56	-101
1024	0.57	-104
1046	0.57	-106
1068	0.57	-110
1090	0.57	-112
1112	0.57	-115
1134	0.57	-118
1156	0.57	-121
1178	0.57	-124
1200	0.57	-127

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SSOP20: plastic shrink small outline package; 20 leads; body width 4.4 mm

SOT266-1



DIMENSIONS (mm are the original dimensions)

UNIT	A max.	A ₁	A ₂	A ₃	b _p	c	D ⁽¹⁾	E ⁽¹⁾	e	H _E	L	L _p	Q	v	w	y	Z ⁽¹⁾	θ
mm	1.5	0.15 0	1.4 1.2	0.25	0.32 0.20	0.20 0.13	6.6 6.4	4.5 4.3	0.65	6.6 6.2	1.0	0.75 0.45	0.65 0.45	0.2	0.13	0.1	0.48 0.18	10° 0°

Note

1. Plastic or metal protrusions of 0.20 mm maximum per side are not included.

OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT266-1						90-04-05 95-02-25

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NOTES

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Data sheet status

Data sheet status	Product status	Definition [1]
Objective specification	Development	This data sheet contains the design target or goal specifications for product development. Specification may change in any manner without notice.
Preliminary specification	Qualification	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.
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[1] Please consult the most recently issued datasheet before initiating or completing a design.

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